

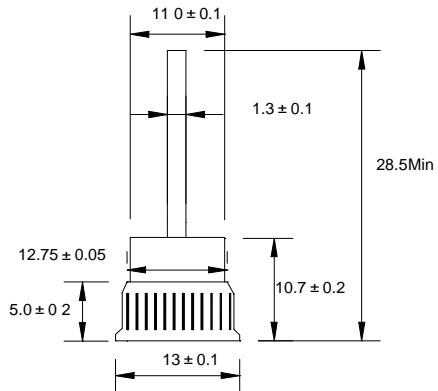
SILICON PRESS-FIT DIODES

VOLTAGE RANGE: 200 -- 600 V
CURRENT: 50 A

FEATURES

- ◇ Nominal current 50A
- ◇ Repetitive peak reverse voltage 600 V
- ◇ Metal press-fit case with plastic cover

ZQL2



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Wire to anode	ZQ50A2L2	ZQ50A4L2	ZQ50A6L2	UNITS
Wire to cathode	ZQ50K2L2	ZQ50K4L2	ZQ50K6L2	
Repetitive peak reverse voltage	V_{RRM}	200	400	600
Surge peak reverse voltage	V_{RSR}	240	480	700
Max. average forward rectified current, R-load @ $T_A=55^\circ C$	$I_{F(AV)}$	50		
Repetitive peak forward current $f > 15\text{Hz}$ (NOTE1)	I_{FRM}	110		
Peak forward surge current, 50/60 Hz half sine-wave	I_{FSM}	450/500		
Forward voltage @ $I_F=50\text{A}$	V_F	1.1		
Leakage current @ $T_j=25^\circ C$	I_R	100		
Rating for fusing $t < 10\text{ms}$	i^2t	800		
Thermal resistance junction to case	R_{thc}	0.7		
Operating junction temperature	T_j	- 55 --- + 215		
Storage temperature range	T_s	- 55 --- + 215		

NOTE: Max.case temperature $T_c=150^\circ C$ -Max.

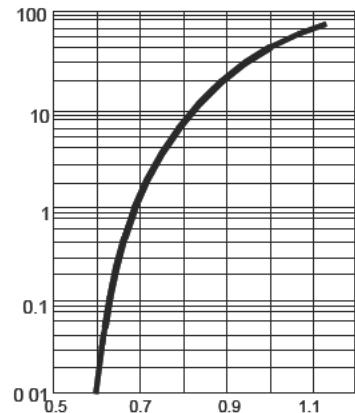
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RATINGS AND CHARACTERISTIC CURVES

ZQ50A2L2---ZQ50K6L2

FIG.1 – TYPICAL FORWARD CHARACTERISTIC

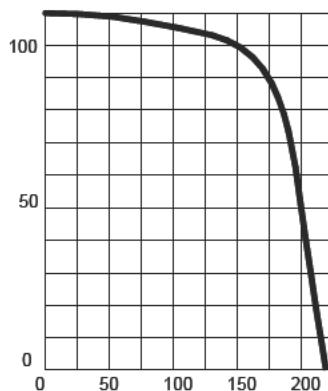
INSTANTANEOUS FORWARD CURRENT
AMPERES



INSTANTANEOUS FORWARD VOLTAGE, VOLTS

FIG.2 – FORWARD DERATING CURRENT

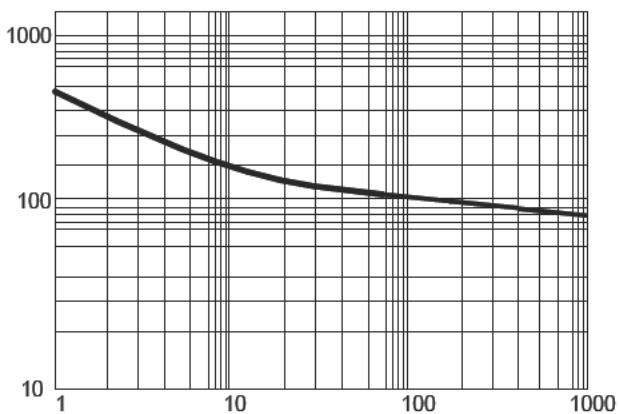
RATED FORWARD CURRENT VS.%



CASE TEMPERATURE, °C

FIG.3 – PEAK FORWARD SURGE CURRENT

PEAK FORWARD SURGE CURRENT
AMPERES



NUMBER OF CYCLES AT 50Hz